



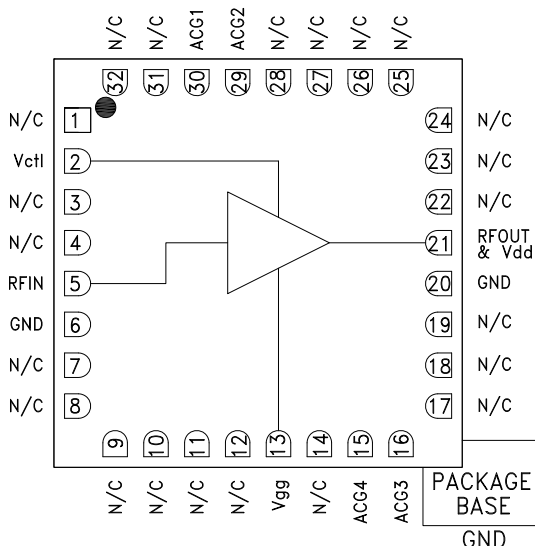
MZ OPTICAL MODULATOR DRIVER, DC - 20 GHz

Typical Applications

The HMC870LC5 is ideal for:

- 10 Gbps NRZ MZ & Low V_{Π} Modulator Driver
- 10 Gbps RZ Transmission
- 40 Gbps DQPSK
- Broadband Gain Block for Test & Measurement Equipment
- Military & Space

Functional Diagram



Features

- Wide Supply Range from 3.3V to 7V
- Adjustable Output Amplitude: 2.5 to 8 Vp-p
- Low Additive RMS Jitter, <300 fs
- Low DC Power Consumption
1W for Vout = 8 Vp-p at Vdd = 7V
- Cross Point Adjustment
- 32 Lead 5x5mm SMT Package: 25mm²

General Description

The HMC870LC5 is a GaAs MMIC pHEMT Distributed Driver Amplifier packaged in a leadless 5x5 mm surface mount package which operates between DC and 20 GHz. The amplifier provides 17 dB of gain, 8Vp-p saturated output swing and features output swing cross point adjustment. Gain flatness is excellent at ± 0.5 dB as well as very low additive RMS jitter of 300 fs for 10 Gbps operation. HMC870LC5 provides Metro and Long Haul designers with scalable power dissipation for varying output drive requirements. (<0.4W at Vout = 3.6 Vp-p and <1W at Vout = 8.5 Vp-p) The HMC870LC5 has a very wide supply (Vdd) operating range from +3.3V to +7V, and the RF I/Os are internally matched to 50 Ohms.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd} = 7\text{V}$, $V_{ctl} = 1\text{V}$, $I_{dd} = 165\text{mA}^*$

Parameter	Conditions	Min.	Typ.	Max.	Units
Gain	Frequency = 1 - 8 GHz	14	17.5		dB
	Frequency = 8 - 16 GHz	13	16.5		dB
	Frequency = 16 - 20 GHz	12	16		dB
Small Signal Bandwidth	3-dB cutoff		20		GHz
Input Return Loss	Frequency = 1 - 10 GHz		20		dB
	Frequency = 10 - 20 GHz		15		dB
Output Return Loss	Frequency = 1 - 10 GHz		20		dB
	Frequency = 10 - 20 GHz		15		dB
Gain Variation over Temperature	Frequency = 1 - 10 GHz		0.015	0.02	dB/ $^\circ\text{C}$
	Frequency = 10 - 20 GHz		0.032	0.045	dB/ $^\circ\text{C}$
Group Delay Variation	Frequency = 1 - 12 GHz		± 15		ps
Saturated Output Power (P _{sat})	Frequency = 1 - 12 GHz		24		dBm
	Frequency = 12 - 20 GHz		23		dBm

* Adjust Vgg between -2V to 0V to achieve Idd = 165 mA typical.

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**MZ OPTICAL MODULATOR
DRIVER, DC - 20 GHz**
Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd} = 7\text{V}$, $V_{ctl} = 1\text{V}$, $I_{dd} = 165\text{mA}$ * Continued

Parameter	Conditions	Min.	Typ.	Max.	Units
Output Power for 1 dB Compression (P1dB)	Frequency = 1 - 12 GHz Frequency = 12 - 20 GHz	19 18	22 21		dBm dBm
Rise Time ^[1]	20% - 80%		20		ps
Fall Time ^[1]	20% - 80%		20		ps
Additive RMS Jitter ^[2]				300	fs
Supply Current (Idd) (Vgg = -0.6V Typ.)			165		mA
Bias Current Adjust (Vgg)		-2		0	V
Output Voltage Adjust (Vctl)		0		2	V

[1] Data input = 22.5 Gbps NRZ PRBS 2²³-1 pattern, 1.2 Vp-p.

[2] RMS jitter is calculated with 22.5 Gbps 10101... pattern.

* Adjust Vgg between -2V to 0V to achieve Idd = 165 mA typical.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd} = 5\text{V}$, $V_{ctl} = 1\text{V}$, $I_{dd} = 140\text{mA}$ *

Parameter	Conditions	Min.	Typ.	Max.	Units
Gain	Frequency = 1 - 8 GHz Frequency = 8 - 16 GHz Frequency = 16 - 20 GHz	14 13.5 12	17.5 17.0 16.5		dB dB dB
Small Signal Bandwidth	3-dB cutoff		20		GHz
Input Return Loss	Frequency = 1 - 10 GHz Frequency = 10 - 20 GHz		20 15		dB dB
Output Return Loss	Frequency = 1 - 10 GHz Frequency = 10 - 20 GHz		15 10		dB dB
Gain Variation over Temperature	Frequency = 1 - 10 GHz Frequency = 10 - 20 GHz		0.016 0.029	0.02 0.045	dB/°C dB/°C
Group Delay Variation	Frequency = 1 - 12 GHz		±15		deg
Saturated Output Power (Psat)	Frequency = 1 - 12 GHz Frequency = 12 - 20 GHz		22.5 22		dBm dBm
Output Power for 1 dB Compression (P1dB)	Frequency = 1 - 12 GHz Frequency = 12 - 20 GHz	18 17	20.5 20		dBm dBm
Rise Time ^[1]	20% - 80%		20		ps
Fall Time ^[1]	20% - 80%		20		ps
Additive RMS Jitter ^[2]				300	fs
Supply Current (Idd) (Vgg = -0.6V Typ.)			140		mA
Bias Current Adjust (Vgg)		-2		0	V
Output Voltage Adjust (Vctl)		0		2	V

[1] Data input = 22.5 Gbps NRZ PRBS 2²³-1 pattern, 1.2 Vp-p.

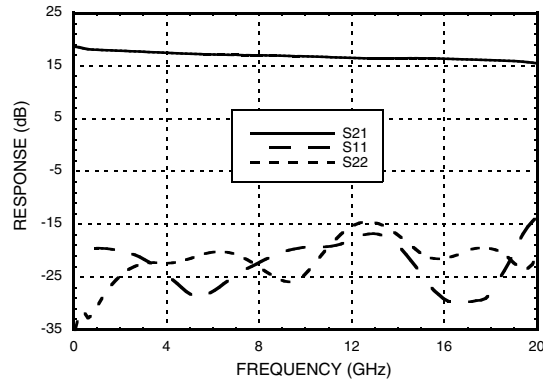
[2] RMS jitter is calculated with 22.5 Gbps 10101... pattern.

* Adjust Vgg between -2V to 0V to achieve Idd = 140 mA typical.

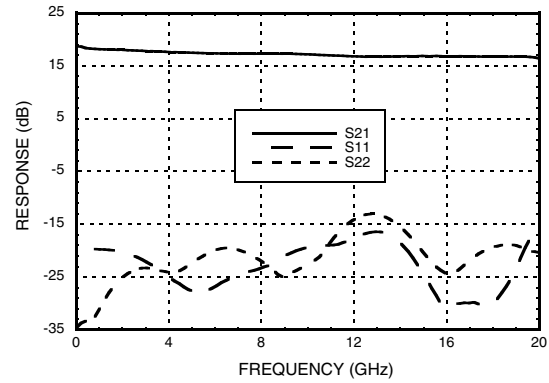


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DRIVER, DC - 20 GHz**

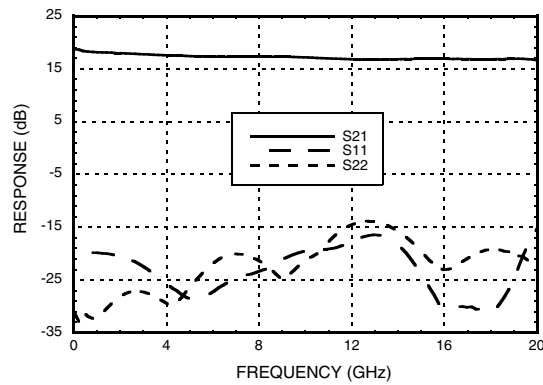
Gain & Return Loss @ Vdd = 7V



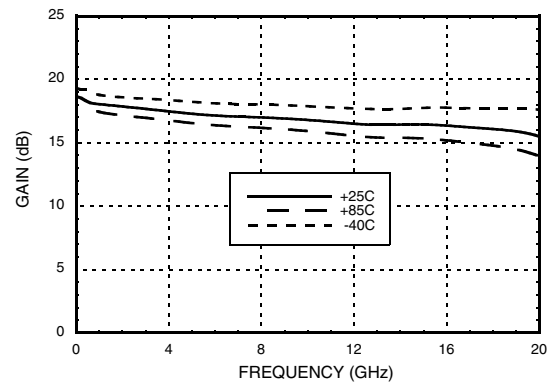
Gain & Return Loss @ Vdd = 5V



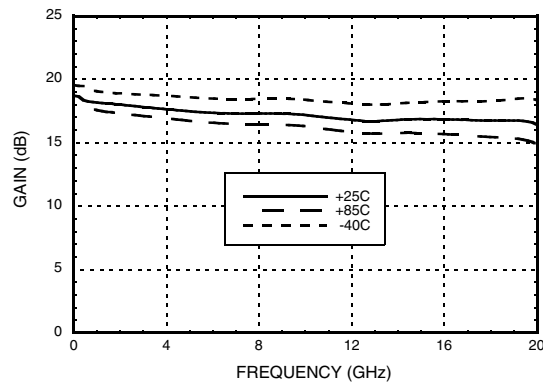
Gain & Return Loss @ Vdd = 3.3V



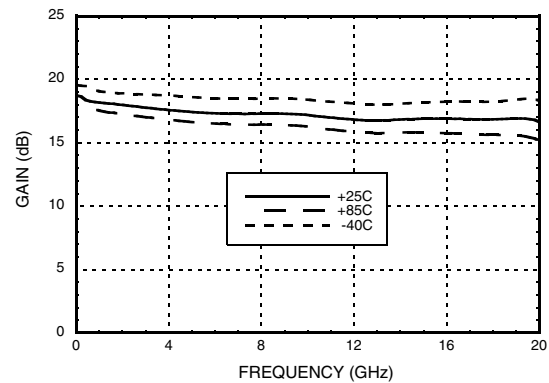
Gain vs. Temperature @ Vdd = 7V

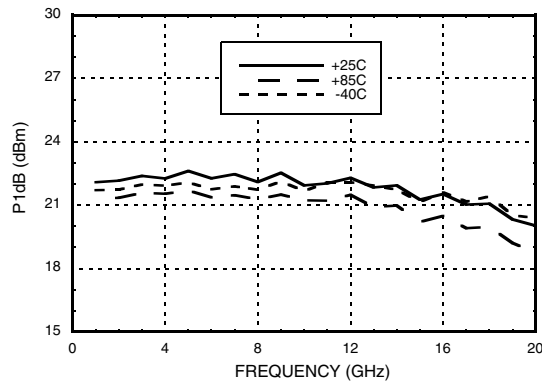
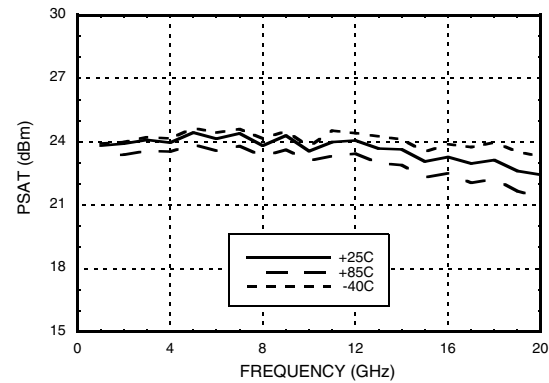
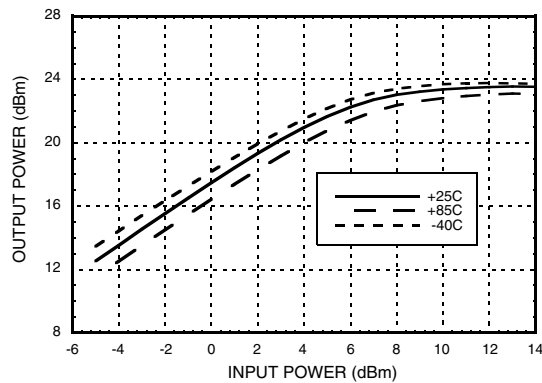
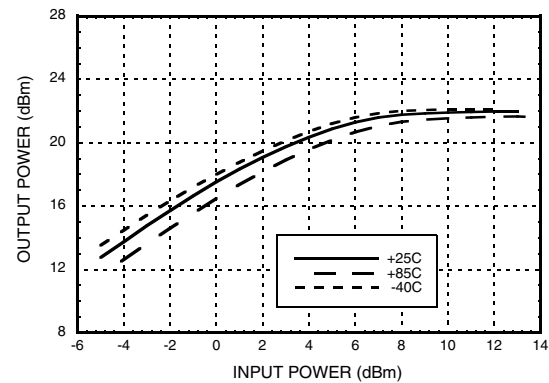
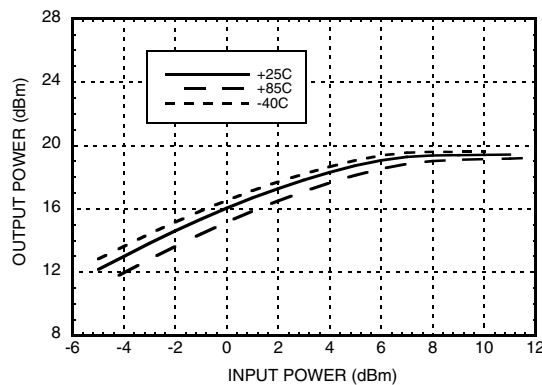
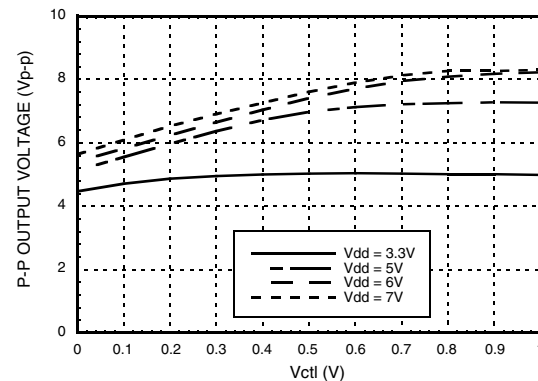


Gain vs. Temperature @ Vdd = 5V

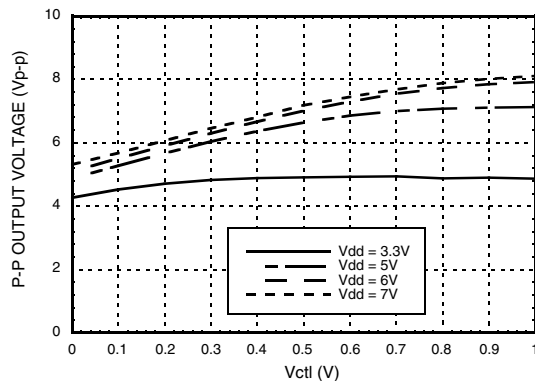
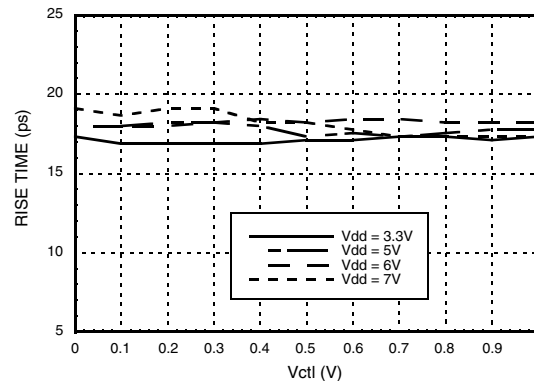
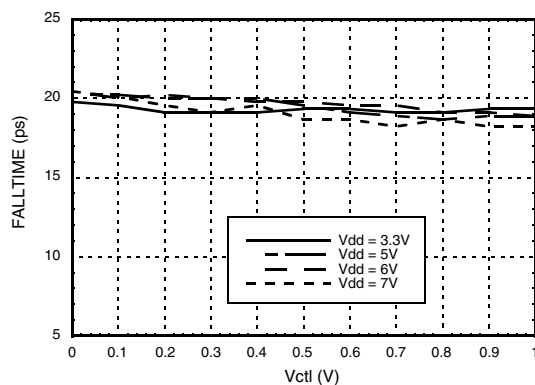
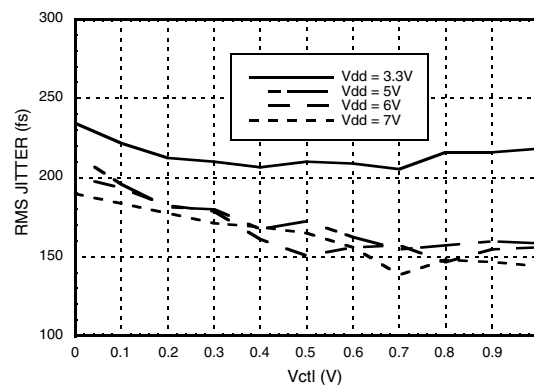
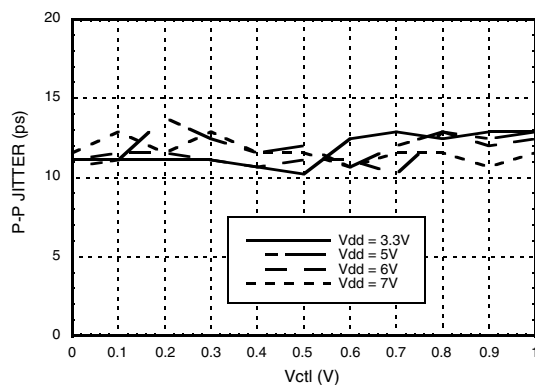
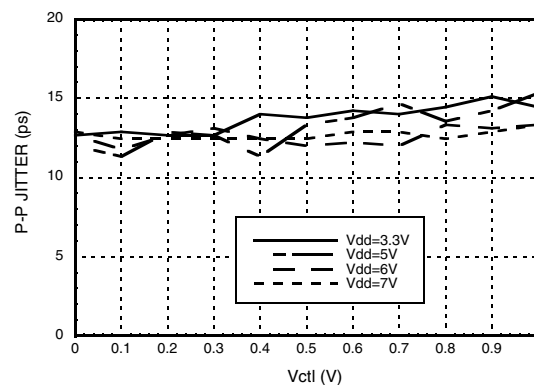


Gain vs. Temperature @ Vdd = 3.3V



**MZ OPTICAL MODULATOR
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P1dB vs. Temperature @ Vdd = 7V

Psat vs. Temperature @ Vdd = 7V

**Output Power vs. Input Power
@ 10 GHz, Vdd = 7V**

**Output Power vs. Input Power
@ 10 GHz, Vdd = 5V**

**Output Power vs. Input Power
@ 10 GHz, Vdd = 3.3V**

**Peak-to-Peak Output Voltage vs.
Vdd @ 11.25 Gbps^[1]**


[1] Data input = 11.25 Gbps NRZ PRBS 2²³-1 pattern, 1.2 Vp-p.

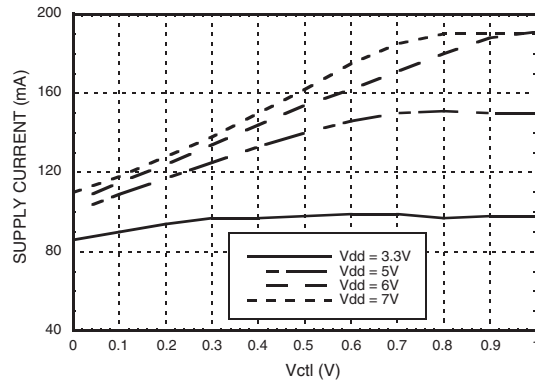

**MZ OPTICAL MODULATOR
DRIVER, DC - 20 GHz**
**Peak-to-Peak Output Voltage vs. Vdd @
22.5 Gbps ^[1]**

Rise Time vs. Vdd @ 22.5 Gbps ^[1]

Fall Time vs. Vdd @ 22.5 Gbps ^[1]

RMS Jitter vs. Vdd @ 22.5 Gbps ^[2]

Peak-to-Peak Jitter vs. Vdd @ 11.25 Gbps ^{[3][4]}

Peak-to-Peak Jitter vs. Vdd @ 22.5 Gbps ^{[1][4]}


[1] Data input = 22.5 Gbps NRZ PRBS 2²³-1 pattern, 1.2 Vp-p.

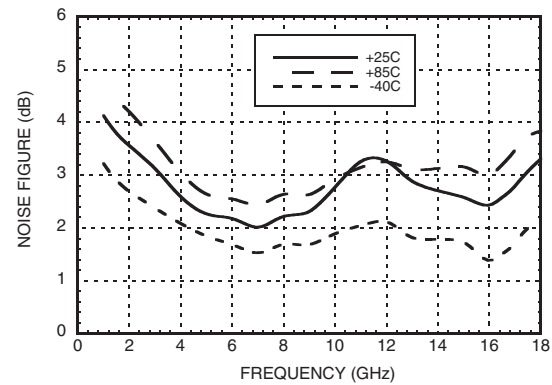
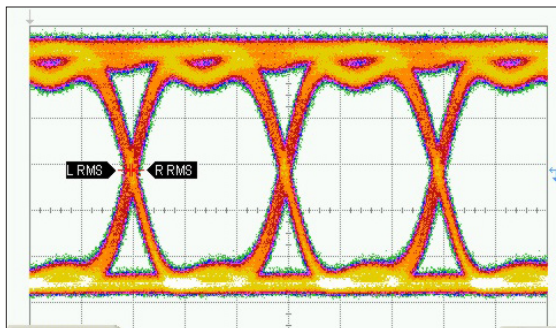
[2] RMS jitter is measured with 22.5 Gbps 10101... pattern.

[3] Data input = 11.25 Gbps NRZ PRBS 2²³-1 pattern, 1.2 Vp-p.

[4] Source jitter was not de-embedded.

**MZ OPTICAL MODULATOR
DRIVER, DC - 20 GHz**
Supply Current vs. Vdd @ 22.5 Gbps [1]


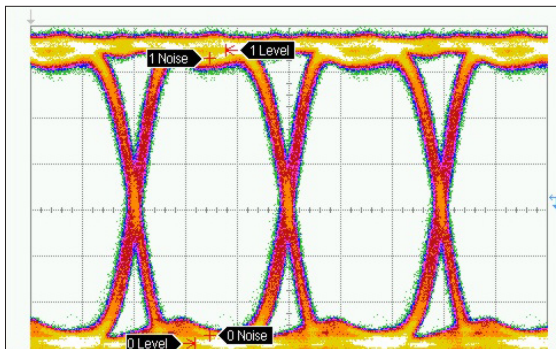
[1] Data Input = 22.5 Gbps NRZ PRBS 223-1 pattern, 1.2 Vp-p

Noise Figure vs. Temperature @ Vdd = 7V

11.25 Gbps NRZ Output Eye Diagram


	Measurements			Units
	Current	Min	Max	
Eye Amplitude	3.6	3.6	3.6	V
Rise Time	20	20	20	ps
Fall Time	21.33	20.67	22	ps
Jitter RMS	1.893	1.87	2.072	ps

Time scale: 30.0 ps/div
Amplitude scale: 762 mV/div

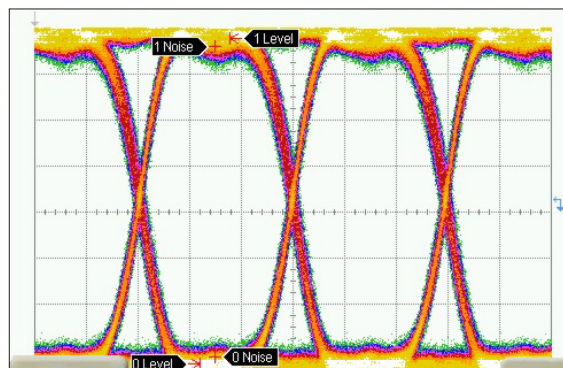
Vdd = 3.3V, Vin: 11.25 Gbps NRZ PRBS 2³¹-1, 0.5 Vp-p
Vout: 3.6Vp-p
Vctl = 1V

11.25 Gbps NRZ Output Eye Diagram


	Measurements			Units
	Current	Min	Max	
Eye Amplitude	7.47	7.47	7.47	V
SNR	17.97	17.88	18.12	V/V

Time scale: 30.0 ps/div
Amplitude scale: 1.17 V/div

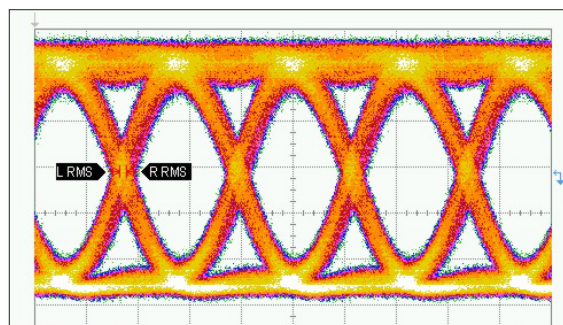
Vdd = 5V, Vin: 11.25Gbps NRZ PRBS 2³¹-1, 1.2V p-p,
Vout: 7.5Vp-p
Vctl = 1V


**MZ OPTICAL MODULATOR
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11.25 Gbps NRZ Output Eye Diagram (Continued)


	Measurements			Units
	Current	Min	Max	
Eye Amplitude	8.26	8.26	8.27	V
SNR	22.35	22.26	22.51	V/V

Time scale: 30.0 ps/div
Amplitude scale: 1.17 V/div

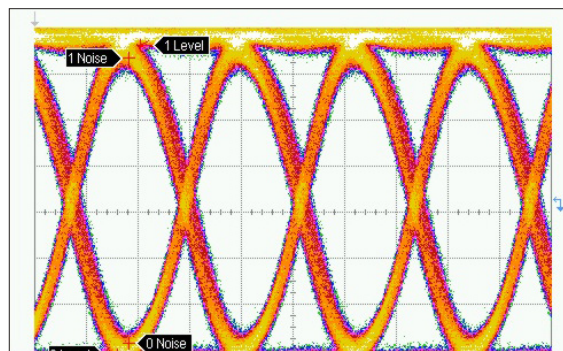
Vdd = 7V, Vin: 11.25Gbps NRZ PRBS 2³¹-1, 1.2V p-p,
Vout: 8.3Vp-p
Vctl = 1V

22.5 Gbps NRZ Output Eye Diagram


	Measurements			Units
	Current	Min	Max	
Eye Amplitude	3.53	3.53	3.54	V
Rise Time	18.22	17.33	18.22	ps
Fall Time	20.44	19.56	20.89	ps
Jitter RMS	2.417	2.187	2.422	ps

Time scale: 20.0 ps/div
Amplitude scale: 762 mV/div

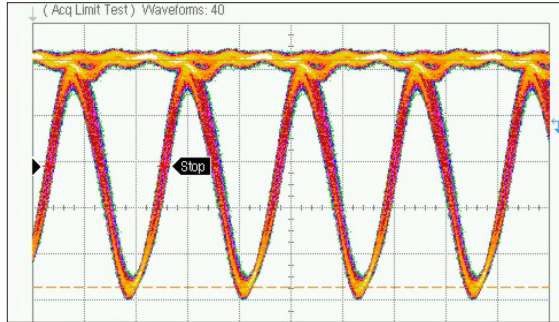
Vdd = 3.3V, Vin: 22.5Gbps NRZ PRBS 2³¹-1, 0.5V p-p,
Vout: 3.5Vp-p
Vctl = 1V

22.5 Gbps NRZ Output Eye Diagram


	Measurements			Units
	Current	Min	Max	
Eye Amplitude	7.85	7.84	7.85	V
SNR	13.74	13.69	14.07	V/V

Time scale: 20.0 ps/div
Amplitude scale: 1.17 V/div

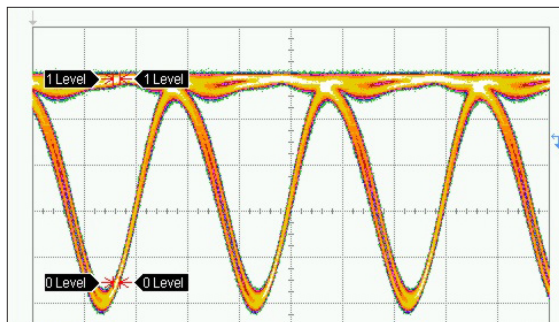
Vdd = 7V, Vin: 22.5Gbps NRZ PRBS 2³¹-1, 1.2 V p-p,
Vout: 7.9Vp-p
Vctl = 1V

**MZ OPTICAL MODULATOR
DRIVER, DC - 20 GHz**
11.25 Gbps RZ Output Eye Diagram


Measurements		
	Current	Units
Jitter RMS	1.93	ps
Bit Rate	11.2	Gb/s

Time scale: 40.0 ps/div
Amplitude scale: 1.22 V/div

Vdd = 3.3V, Vin: 11.25Gbps RZ PRBS 2³¹-1, 0.3V p-p,
Vout: 2.9Vp-p
Vctl = 1V

11.25 Gbps RZ Output Eye Diagram


Measurements				
	Current	Min	Max	Units
Duty Cycle	51.5	50.4	57.1	%
SNR	20.85	13.35	20.96	V/V
Jitter RMS	1.753	1.689	1.795	ps
Eye Amplitude	2.85	2.37	2.86	V

Time scale: 30.0 ps/div
Amplitude scale: 647 mV/div

Vdd = 5V, Vin: 11.25Gbps RZ PRBS 2³¹-1, 1.2V p-p,
Vout: 6Vp-p
Vctl = 1V

Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+9V
Gate Bias Voltage (Vgg)	-2V to 0V
Control Bias Voltage (Vctl)	(Vdd -7) to Vdd (V)
RF Input Power (RFIN)(Vdd = +7 Vdc)	+23 dBm
Channel Temperature	175 °C
Continuous P _{diss} (T = 85 °C) (derate 24 mW/°C above 85 °C)	1.5 W
Thermal Resistance (channel to ground paddle)	59.4 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

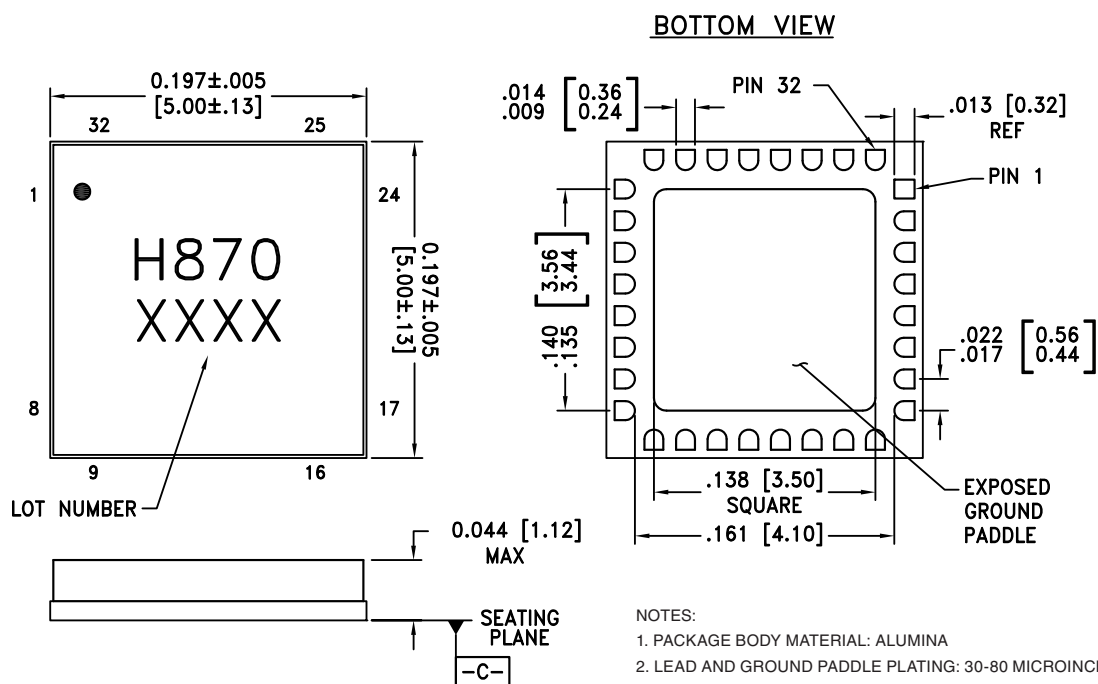
Typical Supply Current vs. Vdd*

Vdd (V)	I _{dd} (mA)*	Power Dissipation (W)
+3.3	100	0.33
+5.0	140	0.70
+6.0	160	0.96
+7.0	165	1.115

* Adjust Vgg between -2V to 0V to achieve I_{dd} shown.



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

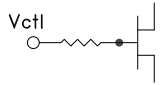
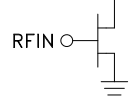
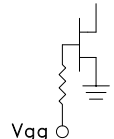
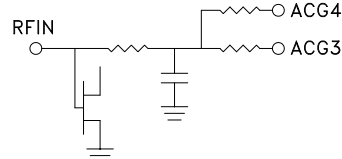
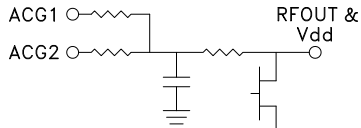
**MZ OPTICAL MODULATOR
DRIVER, DC - 20 GHz**
Outline Drawing**Package Information**

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC870LC5	Alumina, White	Gold over Nickel	MSL3 ^[1]	H870 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

Pin Descriptions

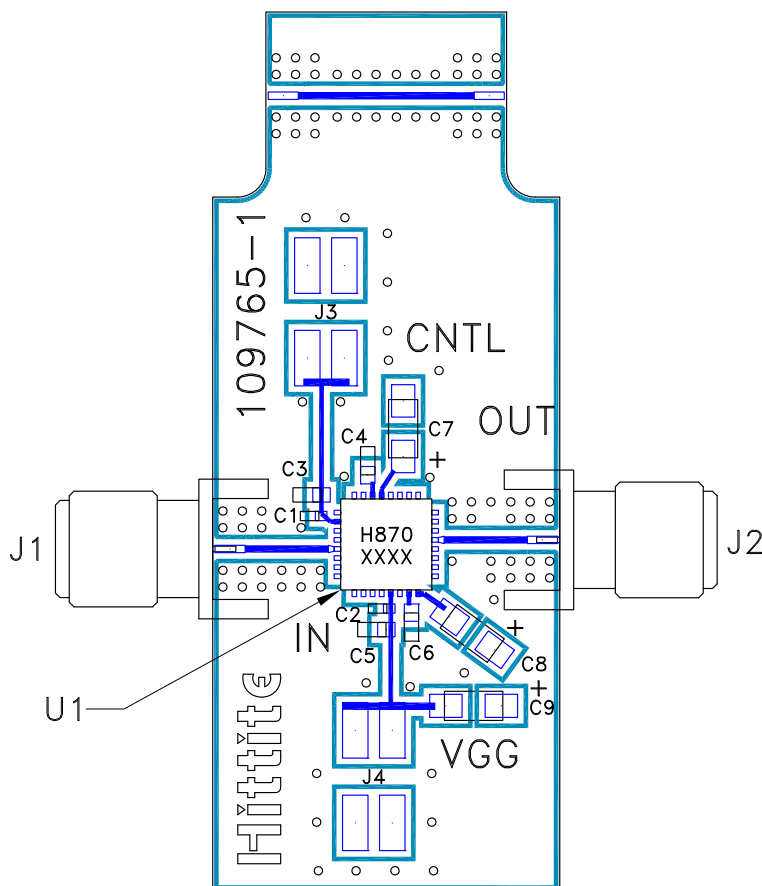
Pin Number	Function	Description	Interface Schematic
1, 3, 4, 7 - 12, 14, 17 - 19, 22 - 28, 31, 32	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
2	Vctl	Output voltage swing adjustment. +1V should be applied to Vctl for nominal operation.	
5	RFIN	This pin is DC coupled and matched to 50 Ohms.	
6, 20	GND	RF/DC Ground. These pins and the package base must be connected to RF/DC ground.	
13	Vgg	Gate Control for amplifier.	
15	ACG4	Low frequency termination. Attach bypass capacitor per application circuit herein.	
16	ACG3		
21	RFOUT & Vdd	RF output for amplifier. Connect the DC bias (Vdd) network to provide drain current (Idd). See application circuit herein.	
29	ACG2	Low frequency termination. Attach bypass capacitor per application circuit herein.	
30	ACG1		

[illegible]

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Evaluation PCB



List of Materials for Evaluation PCB 108347 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J4	2mm Molex Header
C1, C2	100 pF Capacitor, 0402 Pkg.
C3 - C6	1000 pF Capacitor, 0603 Pkg.
C7 - C9	4.7 μF Capacitor, Tantalum
U1	HMC870LC5, Modulator Driver
PCB [2]	109765 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.



MZ OPTICAL MODULATOR DRIVER, DC - 20 GHz

Device Operation

These devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.

The input to this device should be AC-coupled. To provide the typical 8Vp-p output voltage swing, a 1.2Vp-p AC-coupled input voltage swing is required.

Device Power Up Instructions

1. Ground the device
 2. Set V_{gg} to -2V (no drain current)
 3. Set V_{ctl} to +1V (no drain current)
 4. Set V_{dd} to +5V (no drain current)
 5. Adjust V_{gg} for I_{dd} = 140mA
- V_{gg} may be varied between -1V and 0V to provide the desired eye crossing point percentage (i.e. 50% crosspoint) and a limited cross point control capability.
 - V_{dd} may be increased to +7V if required to achieve greater output voltage swing.
 - V_{ctl} may be adjusted between +2V and +0V to vary the output voltage swing.

Device Power Down Instructions

1. Reverse the sequence identified above in steps 1 through 4.

**MZ OPTICAL MODULATOR
DRIVER, DC - 20 GHz**

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Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9